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To:	Examiner C.Q. Nguyen Group Art Unit: 2811	From:	Leslie S. Szivos, Ph.D.			
Fax:	703-872-9306	Pages:	16 including cover			
Phone	· *	Date:	5/31/2005			
Re:	Tze-chiang Chen, et al. U.S. Patent Appln. No. 10/700,085 Our Docket: YOR920030586US1 (CG: 17201)				
XX Un	gent 🗆 For Review 🗀 Please	e Comment	☐ Please Reply	☐ Please Recycle		
Dear S	ir:					
The fo	llowing is attached hereto:		·			
. 1	Amendment Transmittal in dunlicate	•				

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CERTIFICATE OF TRANSMISSION BY FACSIMILE (37 CFR 1.8) Applicant(s): Tze-Chiang Chen, et al. Docket No. YOR920030586US1 (17201)							
10K920030300USI (1720I)							
Application No.	Filing Date	Examiner		Group Art Unit			
10/700,085	11/3/2003	C.Q. Nguyen		2811			
11/3/2003		O.Q. riguyun		2011			
Invention: METHOD FOR FABRICATING SiGe-ON-INSULATOR (SGOI) AND Ge-ON-INSULATOR (GOI) SUBSTRATES							
I hereby certify that this RESPONSE UNDER 37 CFR §1.111 (Identify type of correspondence)							
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AMENDMENT TRANSMITTAL LETTER (Large Entity Applicant(s):)	Docket No. YOR920030586US1 (17201)		
Application No. 10/700,085	Filing Date 11/3/2003	Examiner C.Q. Nguyen		omer No. 23389	Group Art Unit	Confirmation No. 2805	
Invention: METHOD FOR FABRICATING SiGe-ON-INSULATOR (SGOI) AND Ge-ON-INSULATOR (GOI) SUBSTRATES							
	COMMISSIONER FOR PATENTS:						
1		n the above-identified a mitted as shown below.	-				
		CLAIMS AS AM	ENDED				
	CLAIMS REMAINING AFTER AMENDMENT	HIGHEST # PREV. PAID FOR	NUMBER EXT		RATE	ADDITIONAL FEE	
TOTAL CLAIMS	36 -	68 =	0	х	\$50.00	\$0.00	
INDEP. CLAIMS	3 -	6 =	0	x	\$200.00	\$0.00	
Multiple Dependent	\$0.00						
		TOTAL ADDITIONAL F	EE FOR TH	IS AMENI	OMENT	\$0.00	
No additional fee is required for amendment. Please charge Deposit Account No. in the amount of A check in the amount of to cover the filing fee is enclosed. The Director is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account 50-0510/IBM Any additional filing fees required under 37 C.F.R. 1.16. Any patent application processing fees under 37 CFR 1.17. Payment by credit card. Form PTO-2038. WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038.							
Leslie S. Szivos, Ph.D. Reg. No. 39,394 hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as find class final in an envelope addressed to "Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450" [37 CFR 1.8(a)] on (Date) Signature of Person Mailing Correspondence Typed or Printed Name of Person Mailing Correspondence Typed or Printed Name of Person Mailing Correspondence							

AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s):					Docket No. YOR920030586US1 (17201)		
Application No. 10/700,085	Filing Date 11/3/2003	Examiner C.Q. Nguyen	Custome 2338		Group Art Unit	Confirmation No. 2805	
Invention: METHOD FOR FABRICATING SIGE-ON-INSULATOR (SGOI) AND GE-ON-INSULATOR (GOI) SUBSTRATES							
COMMISSIONER FOR PATENTS:							
Transmitted herewith is an amendment in the above-identified application. The fee has been calculated and is transmitted as shown below.							
		CLAIMS AS AM	ENDED				
	CLAIMS REMAINING AFTER AMENDMENT	HIGHEST # PREV. PAID FOR	NUMBER EXTRA		RATE	ADDITIONAL FEE	
TOTAL CLAIMS	36 -	68 =	0	×	\$50.00	\$0.00	
INDEP. CLAIMS	3 -	6 =	0	x	\$200.00	\$0.00	
Multiple Dependent Claims (check if applicable)						\$0.00	
	TOTAL ADDITIONAL FEE FOR THIS AMENDMENT \$0.0						
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Reg. No. 39,394 Thereby certify that this the United States Postal class mall in an envelope P.O. Box 1450, Alexandria (Date) Signature of Postal class mall in an envelope P.O. Box 1450, Alexandria					Service with suffaddressed to "Con, VA 22313-1450"	icient postage as first nmissioner for Patents, [37.2 FR 1.8(a)] on	

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Tze-chiang Chen, et al.

Examiner: C.Q. Nguyen

Serial No:

10/700,085

Art Unit: 2811

Filed:

November 3, 2003

Docket: YOR920030586US1 (17201)

Dated:

May 31, 2005

For: METHOD FOR FABRICATING SiGe-ON-INSULATOR (SGOI) AND

Ge-ON-INSULATOR (GOI) SUBSTRATES

Confirmation No. 2805

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Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450 MAY 3 1 2005

RESPONSE UNDER 37 C.F.R. § 1.111

Sir:

In response to the Office Action dated February 28, 2005, applicants submit the following amendments and remarks for entry of record in the above-identified patent application.

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that this paper is being facsimile transmitted to the Patent and

Trademark Office on the date shown below.

Dated: May 31, 2005

Leslie S. Szivos, Ph.D.